

# Time-frequency characterization of magnetization dynamics in spin-torque oscillators

Giulio Siracusano<sup>1</sup>, Giovanni Finocchio<sup>1</sup>, Aurelio La Corte<sup>2</sup>, Luis Torres<sup>3</sup>, Bruno Azzerboni<sup>1</sup>

We first introduce a time-frequency characterization of magnetization dynamics driven by spin-polarized current in spin-torque oscillators. It is based on the continuous wavelet transform, with a systematic identification of the scale set  $\{s_i\}_{i=1..N}$ . We use the complex Morlet [1] wavelet  $\psi$ , this yields the corresponding wavelet family function  $\psi_{u,s}$ :

$$\psi_{u,s} = \frac{1}{\sqrt{s\pi f_B}} e^{j2\pi f_C \left(\frac{t-u}{s}\right)} e^{-\frac{1}{f_B} \left(\frac{t-u}{s}\right)^2} \quad (1)$$

where  $s$  and  $u$  are the scale and translation parameter, respectively, while  $f_C$  and  $f_B$  are characteristic parameters [1]. This wavelet-based approach generalizes the micromagnetic spectral mapping technique and, together with micromagnetic simulations, can be used to characterize the spin-torque oscillator dynamics completely. It is able to reproduce the frequency and power modulation claimed in stochastic theory developed by Kim in Ref. [2].

We reproduce the time-frequency behavior of measurements reported in [3] of the real-time voltage signal captured by a microwave storage oscilloscope. The device under investigation is a nanoscale spin valve Py(4nm) (free layer) / Cu(8nm) / Py(4nm) (pinned layer) / Ir<sub>20</sub>Mn<sub>80</sub>(8nm) (Py=Ni<sub>80</sub>Fe<sub>20</sub>) exchange biased with elliptical cross sectional area of 130 nm × 60 nm. We consider an applied current  $I=4.5$  mA and external field  $H=60$  mT. The power spectra shows two main frequencies  $f_{P1}=3.9$  GHz and  $f_{P2}=4.6$  GHz (for a signal of 20 ns, these two modes are also measured at second scale), performing the Fourier transform with a window time of 4 ns it can be observed either P<sub>1</sub> or P<sub>2</sub>, this result shows the non-periodic origin of this magnetization precession (see fig. 6 in Ref[3]). Those results have been confirmed by our wavelet analysis as displayed in Fig 1. It shows the wavelet scalogram (arb. units) computed for the voltage signal of Fig. 6 in Ref.[3]. We use the following parameters: a set of scale parameters with  $N = 22$  elements,  $f_B = 300$  and  $f_C = 1$ . As can be noted, the results of our computations are consistent with

the data displayed in Fig. 6 of Ref. [3]. Indeed the wavelet scalogram can show much more details, for example the decreasing of the output power of microwave signal close 16 ns and the presence of the P<sub>2</sub> mode in 9-14 ns.

Finally, we performed a complete micromagnetic study of the non-stationary magnetization dynamics as function of field amplitude and angle, current and temperature. Our simulations take into account current-induced motion of not only the free but also the pinned ferromagnetic layer of the spin valve[4].

Our main results are: (i) exist magnetization oscillations with thermally-induced mode hopping behavior at the nanosecond time scale below a sub-critical current; (ii) a non-stationary behavior can be observed for non-collinear configuration of magnetization of pinned and free layer; (iii) as the field amplitude increases the frequency of two excited modes tend to be closer and, for a critical value of current, a single mode dynamics is driven (large amplitude magnetization oscillation).

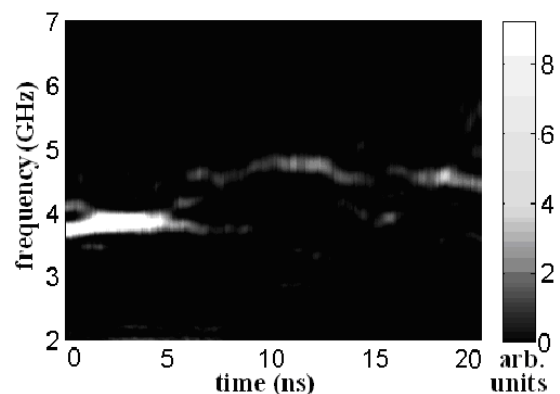


Fig. 1- Wavelet scalogram computed for the time-trace displayed in Fig. 6 of Ref. [2].

A complete dynamical stability diagram will be presented in the full paper.

## REFERENCES

- [1] A. Teolis, Computational signal processing with wavelets, Birkhauser, 1998.
- [2] J.-V. Kim, *Phys. Rev. B* **73**, 174412 (2006).
- [3] I. Krivorotov, N.C. Emley, R.A. Buhman, D.C. Ralph, *Phys. Rev. B* **77**, 054440 (2008).
- [4] G. Siracusano, G. Finocchio, I. N. Krivorotov, L. Torres, G. Consolo, B. Azzerboni, *J. Appl. Phys.* **105**, 07D107 (2009).

<sup>1</sup> Department of Fisica della Materia e Ingegneria Elettronica, University of Messina, Salita Sperone 31, 98166 Messina Italy.

E-mail: gsiracusano@unime.it (Corresponding Author).

<sup>2</sup> Department of Informatic Engineering and Telecommunications. University of Catania. Viale Andrea Doria, 6 – 95125 Catania, Italy.

<sup>3</sup> Department of Fisica Aplicada, Universidad de Salamanca, Plaza de la Merced, Salamanca 37008, Spain.